## NSN 5961-01-310-9404

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Function For Which Designed:
Amplifier
nternal Configuration:
Field effect
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
20.0 gate to source voltage and 80.0 drain to source voltage and 80.0 drain to gate voltage and 80.0 breakdown voltage, drain-to-source
with all other terminals short-circuited to source and 2.0 gate to source threshold voltage and 6.0 gate to source threshold voltage
Current Rating Per Characteristic:
2.00 amperes drain current and 1.80 amperes on-state drain current
Power Rating Per Characteristic:
40.0 watts total device dissipation
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
Yes - demil/mli
Filg:
A110a0